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FAIRCHILD SEMICONDUCTOR IM

FDS6576

P-Channel 2.5V Specified PowerTrench[®] MOSFET **General Description Features**

This P-Channel 2.5V specified MOSFET is in a rugged gate version of Fairchild Semiconductor's advanced PowerTrench[®] process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

Applications

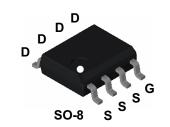
- Load switch
- Battery protection
- Power management

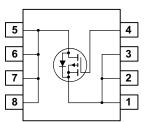


-11 A, -20 V. $R_{DS(ON)}$ = 0.014 Ω @ V_{GS} = -4.5 V

 $R_{DS(ON)} = 0.020 \ \Omega @ V_{GS} = -2.5 \ V$

- Extended V_{GSS} range (±12V) for battery applications.
- Low gate charge (43nC typical).
- Fast switching speed.
- High performance trench technology for extremely low R_{DS(ON)}.
- High power and current handling capability.
- RoHS Compliant.





Absolute Maximum Ratings T_A=25°C unless otherwise noted

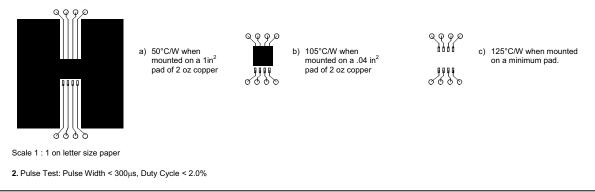
Symbol	Parameter			Ratings	Units	
V _{DSS}	Drain-Source	ce Voltage		-20	V	
V _{GSS}	Gate-Sourc	e Voltage		± 12	V	
I _D	Drain Curre	nt – Continuous	(Note 1a)	–11	А	
		– Pulsed		-50		
P _D	Power Diss	ipation for Single Operation	(Note 1a)	2.5	W	
			(Note 1b)	1.2		
			(Note 1c)	1.0		
T _J , T _{STG}	Operating a	perating and Storage Junction Temperature Range		-55 to +150	°C	
Therma	I Charac	teristics				
R _{0JA}	Thermal Resistance, Junction-to-Ambient (No		It (Note 1a)	50	°C/W	
R _{0JA}	Thermal Re	Thermal Resistance, Junction-to-Ambient (Note 1c)		125	°C/W	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 1)		(Note 1)	25	°C/W	
Packag	e Marking	g and Ordering Inf	ormation			
Device Marking		Device	Reel Size	Tape width	Quantity	
Device	nannig					

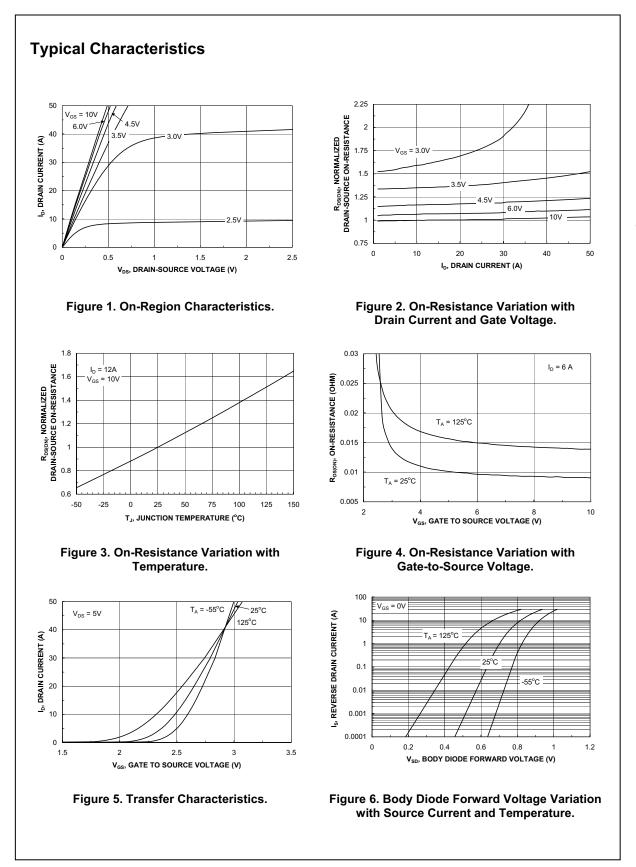
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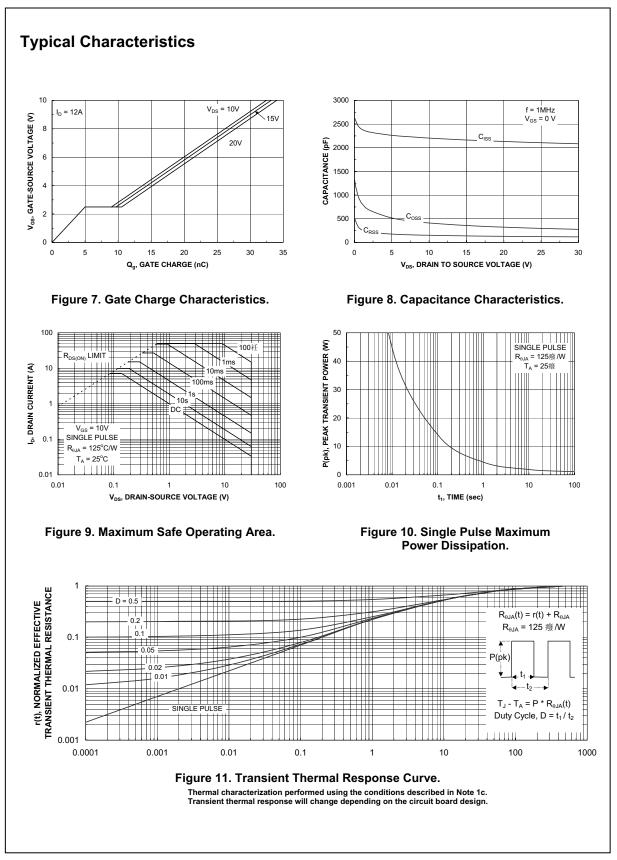
December 2006

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient	I_D = –250 µA, Referenced to 25°C		-13		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16 V, V_{GS} = 0 V$			-1	μA
I _{GSSF}	Gate-Body Leakage, Forward	-Body Leakage, Forward $V_{GS} = 12 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
I _{GSSR}	Gate–Body Leakage, Reverse	$V_{GS} = -12 V, V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.6	-0.83	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = -250 µA, Referenced to 25°C		3.5		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{ll} V_{GS} = -4.5 \ V, & I_D = -11 \ A \\ V_{GS} = -2.5 \ V, & I_D = -8.8 \ A \\ V_{GS} = -4.5 \ V, \ I_D = -11 \ A, \ T_J = 125^\circ C \end{array} $		8.2 11.5 11.1	14 20 23	mΩ
D(on)	On–State Drain Current	$V_{GS} = -4.5 V$, $V_{DS} = -5 V$	-25			А
g _{FS}	Forward Transconductance	$V_{DS} = -4.5 V$, $I_D = -11 A$		50		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		4044		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		955		pF
C _{rss}	Reverse Transfer Capacitance			504		pF
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -10 V, I_D = -1 A,$		18	32	ns
t _r	Turn–On Rise Time	$V_{\rm GS} = -4.5 \text{ V}, \qquad \qquad R_{\rm GEN} = 6 \ \Omega$		17	31	ns
t _{d(off)}	Turn–Off Delay Time			124	198	ns
t _f	Turn–Off Fall Time			79	126	ns
Qg	Total Gate Charge	$V_{DS} = -10 V$, $I_D = -11 A$,		43	60	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		7		nC
Q _{gd}	Gate–Drain Charge			12		nC
Drain–So	ource Diode Characteristics	and Maximum Ratings				
ls	Maximum Continuous Drain-Source				-2.1	A
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -2.1 A$ (Note 2)		-0.66	-1.2	v

the drain pins. $\rm R_{\theta JC}$ is guaranteed by design while $\rm R_{\theta CA}$ is determined by the user's board design.







FDS6576 P-Channel 2.5V Specified PowerTrench[®] MOSFET

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